

Vishay General Semiconductor

Surface Mount PAR® Transient Voltage Suppressors

High Temperature Stability and High Reliability Conditions





PRIMARY CHARACTERISTICS					
V_{WM}	10 V to 36 V				
V_{BR}	11.1 V to 44.2 V				
P _{PPM} (10 x 1000 μs)	3600 W				
P _{PPM} (10 x 10 000 μs)	2800 W				
P_{D}	5 W				
I _{FSM}	500 A				
T _J max.	175 °C				
Polarity	Unidirectional				
Package	DO-218AB				

FEATURES

 Junction passivation optimized design passivated anisotropic rectifier technology



 T_J = 175 °C capability suitable for high reliability and automotive requirement

- Available in unidirectional polarity only
- Low leakage current
- Low forward voltage drop
- · High surge capability
- Meets ISO7637-2 surge specification (varied by test condition)
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting, especially for automotive load dump protection application.

MECHANICAL DATA

Case: DO-218AB

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3_X - RoHS-compliant and AEC-Q101 qualified ("X" denotes revision code e.g. A, B, ...)

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

HE3 suffix meets JESD 201 class 2 whisker test

Polarity: heatsink is anode

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	VALUE	UNIT			
Peak pulse power dissipation	with 10/1000 µs waveform	Б	3600	W		
	with 10/10 000 µs waveform	P _{PPM}	2800			
Power dissipation on infinite heatsink at T _C = 25 °C (fig. 1)		P _D	5.0	W		
Peak pulse current with 10/1000 µs waveform		I _{PPM} ⁽¹⁾	See next table	А		
Peak forward surge current 8.3 m	I _{FSM}	500	А			
Operating junction and storage te	T _J , T _{STG}	-55 to +175	°C			

Note

(1) Non-repetitive current pulse at T_A = 25 °C



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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)										
DEVICE	REAKDOWN VOLTAGE V _{BR} (V)		TEST CURRENT	STAND- OFF VOLTAGE	MAXIMUM REVERSE LEAKAGE	MAXIMUM REVERSE LEAKAGE	MAX. PEAK PULSE CURRENT	MAXIMUM CLAMPING VOLTAGE	TYPICAL TEMP. COEFFICIENT OF V _{BR} (1)	
TYPE	MIN.	NOM.	MAX.	I _T (mA)	V _{WM} (V)	AT V _{WM} I _D (μΑ)	AT V _{WM} T _J = 175 °C I _D (μA)	AT 10/1000 µs WAVEFORM (A)	AT I _{PPM} V _C (V)	α Τ (%/°C)
SM5S10A	11.1	11.7	12.3	5.0	10.0	15	250	212	17.0	0.069
SM5S11A	12.2	12.9	13.5	5.0	11.0	10	150	198	18.2	0.072
SM5S12A	13.3	14.0	14.7	5.0	12.0	10	150	181	19.9	0.074
SM5S13A	14.4	15.2	15.9	5.0	13.0	10	150	167	21.5	0.076
SM5S14A	15.6	16.4	17.2	5.0	14.0	10	150	155	23.2	0.078
SM5S15A	16.7	17.6	18.5	5.0	15.0	10	150	148	24.4	0.080
SM5S16A	17.8	18.8	19.7	5.0	16.0	10	150	138	26.0	0.081
SM5S17A	18.9	19.9	20.9	5.0	17.0	10	150	130	27.6	0.082
SM5S18A	20.0	21.1	22.1	5.0	18.0	10	150	123	29.2	0.083
SM5S20A	22.2	23.4	24.5	5.0	20.0	10	150	111	32.4	0.085
SM5S22A	24.4	25.7	26.9	5.0	22.0	10	150	101	35.5	0.086
SM5S24A	26.7	28.1	29.5	5.0	24.0	10	150	93	38.9	0.087
SM5S26A	28.9	30.4	31.9	5.0	26.0	10	150	86	42.1	0.088
SM5S28A	31.1	32.8	34.4	5.0	28.0	10	150	79	45.4	0.089
SM5S30A	33.3	35.1	36.8	5.0	30.0	10	150	74	48.4	0.090
SM5S33A	36.7	38.7	40.6	5.0	33.0	10	150	68	53.3	0.091
SM5S36A	40.0	42.1	44.2	5.0	36.0	10	150	62	58.1	0.091

Notes

To calculate V_{BR} vs. junction temperature, use the following formula: V_{BR} at $T_J = V_{BR}$ at 25 °C x (1 + α T x (T_J - 25))

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	VALUE	UNIT		
Typical thermal resistance, junction to case	$R_{ heta JC}$	1.0	°C/W		

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SM5S10AHE3_A/I (1)	2.505	I	750	13" diameter plastic tape and reel, anode towards the sprocket hole		

Note

(1) AEC-Q101 qualified

[•] For all types maximum V_F = 2.0 V at I_F = 100 A measured on 8.3 ms single half sine-wave or equivalent square wave, duty cycle = 4 pulses per minute maximum

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RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

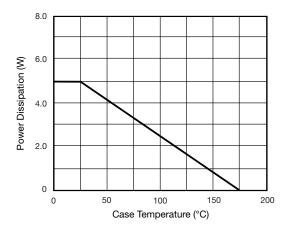


Fig. 1 - Power Derating Curve

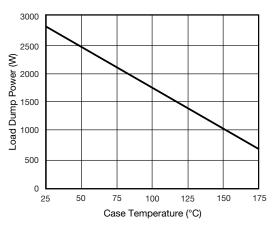


Fig. 2 - Load Dump Power Characteristics (10 ms Exponential Waveform)

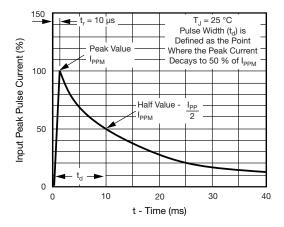


Fig. 3 - Pulse Waveform

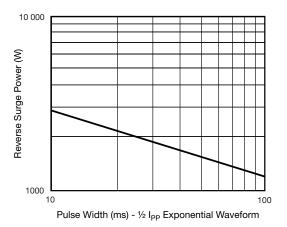


Fig. 4 - Reverse Power Capability

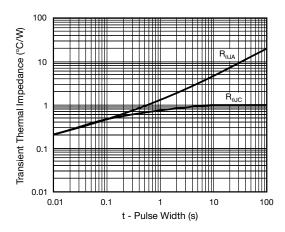
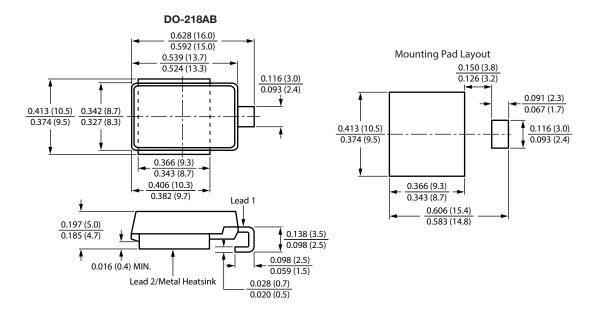


Fig. 5 - Typical Transient Thermal Impedance



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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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